

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Confirmation No. 8121

Kazuyuki NITTA et al.

Docket No. 2001 1143A

Serial No. 09/928,430

Group Art Unit 1752

Filed August 14, 2001

Examiner S. Lee

POSITIVE-WORKING PHOTORESIST COMPOSITION AND RESIST PATTERNING METHOD USING SAME

THE COMMISSIONER IS AUTHORIZED TO CHARGE ANY DEFICIENCY IN THE FEES FOR THIS PAPER TO DEPOSITED ACCOUNT NO. 23-0975

RESPONSE

Assistant Commissioner for Patents, Washington, D.C.

Sir:

In response to the Official Action dated November 6, 2002, please amend the present application as follows:

IN THE CLAIMS:

Please cancel claims 2-4 without prejudice to the subject matter thereof.

Please amend claims 1 and 11 as follows:

1. (Amended) A positive-working photoresist composition which comprises, as a uniform solution in an organic solvent:

- (A) 100 parts by weight of a hydroxystyrene-based polymer which is a combination of:
- (A1) a first polyhydroxystyrene resin having phenolic hydroxyl groups a part of which are substituted for the hydrogen atoms thereof by acid-dissociable alkoxyalkyl groups; and

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